

# DATA SHEET

## **BFQ161** NPN video transistor

Product specification  
Supersedes data of November 1995  
File under Discrete Semiconductors, SC05

1997 Oct 02

## NPN video transistor

## BFQ161

## FEATURES

- Low output capacitance
- High gain bandwidth
- High current applicability
- Good thermal stability
- Gold metallization ensures excellent reliability.

## APPLICATIONS

- Pre-stage driver in high resolution colour graphics monitors.

## DESCRIPTION

NPN video transistor in a SOT54 (TO-92) plastic package.

## PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter

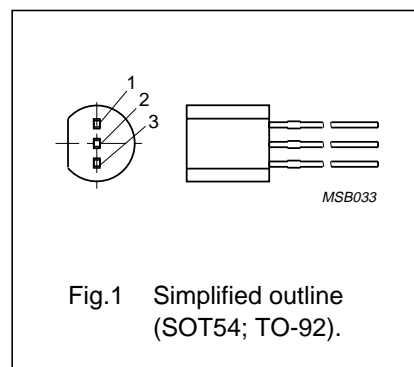


Fig. 1 Simplified outline (SOT54; TO-92).

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	20	V
$V_{CER}$	collector-emitter voltage	$R_{BE} = 100 \Omega$	–	19	V
$I_C$	collector current (DC)		–	500	mA
$P_{tot}$	total power dissipation	$T_s \leq 75 \text{ }^\circ\text{C}$ ; note 1	–	1	W
$h_{FE}$	DC current gain	$I_C = 300 \text{ mA}$ ; $V_{CE} = 5 \text{ V}$	25	–	
$f_T$	transition frequency	$I_C = 300 \text{ mA}$ ; $V_{CE} = 5 \text{ V}$ ; $T_{amb} = 25 \text{ }^\circ\text{C}$	1	–	GHz
$T_j$	junction temperature		–	150	$^\circ\text{C}$

## Note

1.  $T_s$  is the temperature at the soldering point of the collector pin, 4 mm from the body.

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	20	V
$V_{CEO}$	collector-emitter voltage	open base	–	10	V
$V_{CER}$	collector-emitter voltage	$R_{BE} = 100 \Omega$	–	19	V
$V_{EBO}$	emitter-base voltage	open collector	–	3	V
$I_C$	collector current (DC)		–	500	mA
$P_{tot}$	total power dissipation	$T_s \leq 75 \text{ }^\circ\text{C}$ ; notes 1 and 2; see Fig.3	–	1	W
$T_{stg}$	storage temperature range		–65	+150	$^\circ\text{C}$
$T_j$	junction temperature		–	150	$^\circ\text{C}$

## Notes

1.  $T_s$  is the temperature at the soldering point of the collector pin, 4 mm from the body.
2. Transistor mounted on a printed-circuit board with a metallized pad area of 10 mm<sup>2</sup>.

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## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	note 1	75	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient		175	K/W
$R_{th\ s-a}$	thermal resistance from soldering point to ambient		100	K/W

## Note

1.  $T_s$  is the temperature at the soldering point of the collector pin, 4 mm from the body.

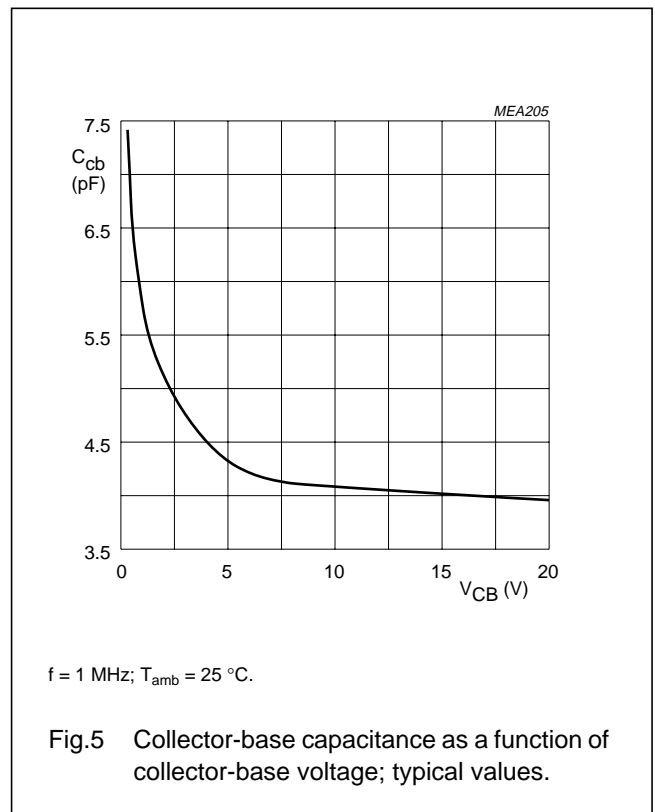
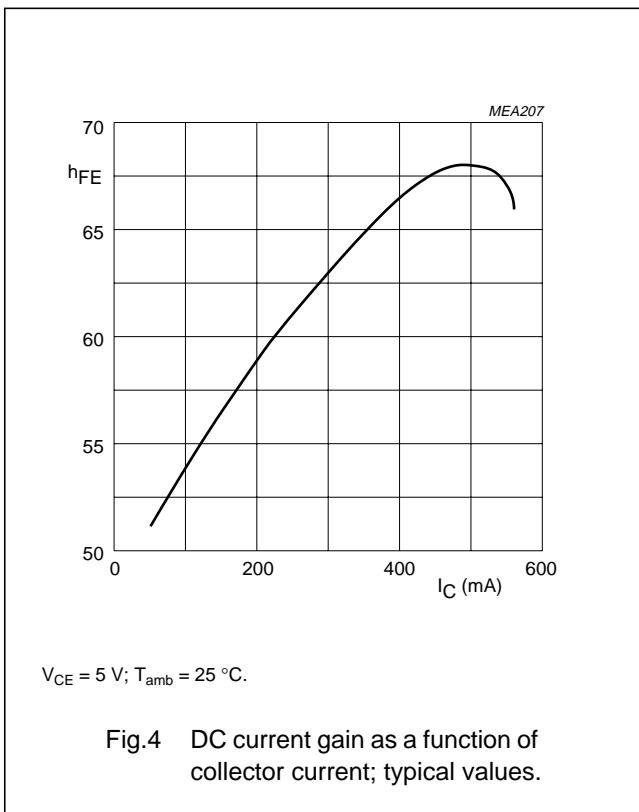
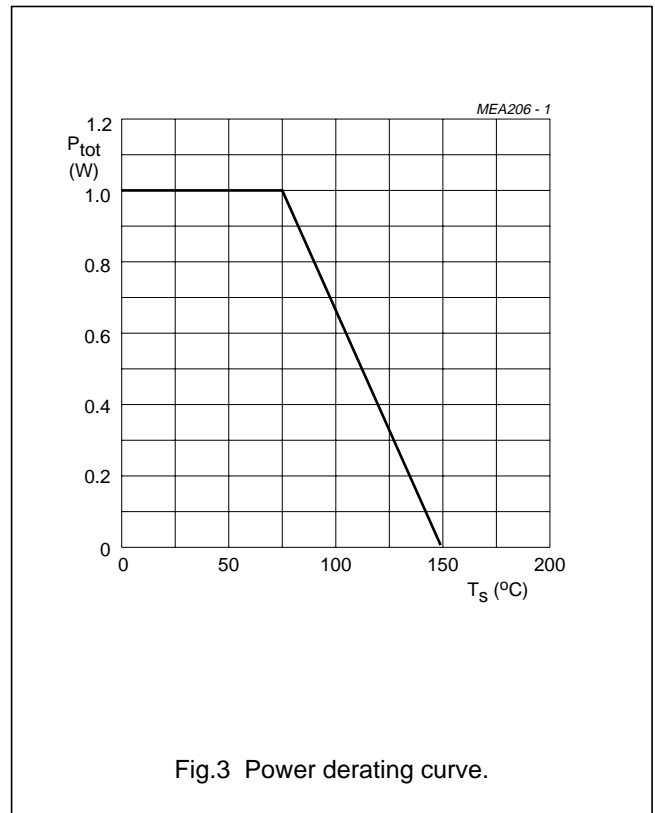
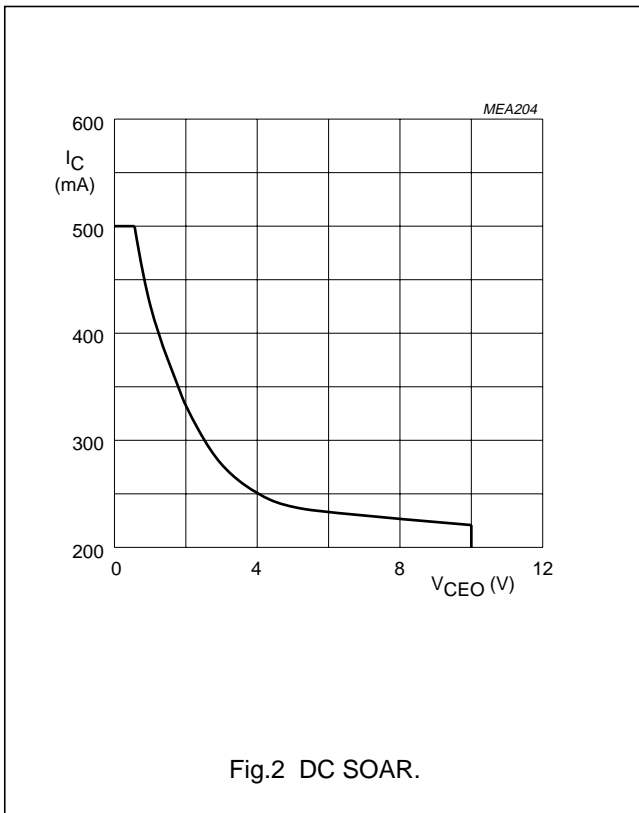
## CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 5\text{ mA}; I_E = 0$	20	–	–	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 10\text{ mA}; I_B = 0$	10	–	–	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_E = 0.1\text{ mA}; I_C = 0$	3	–	–	V
$I_{CES}$	collector-emitter cut-off current	$I_B = 0; V_{CE} = 10\text{ V}$	–	–	100	$\mu\text{A}$
$h_{FE}$	DC current gain	$I_C = 300\text{ mA}; V_{CE} = 5\text{ V};$ $T_{amb} = 25\text{ °C};$ see Fig.4	25	–	–	
		$I_C = 100\text{ mA}; V_{CE} = 5\text{ V};$ $T_{amb} = 25\text{ °C};$ see Fig.4	40	50	–	
$C_{cb}$	collector-base capacitance	$I_C = 0; V_{CB} = 5\text{ V}; f = 1\text{ MHz};$ see Fig.5	–	4.3	–	pF
$C_c$	collector capacitance	$I_E = I_e = 0; V_{CB} = 5\text{ V}; f = 1\text{ MHz}$	–	6	–	pF
$f_T$	transition frequency	$I_C = 300\text{ mA}; V_{CE} = 5\text{ V};$ see Fig.6	1	–	–	GHz

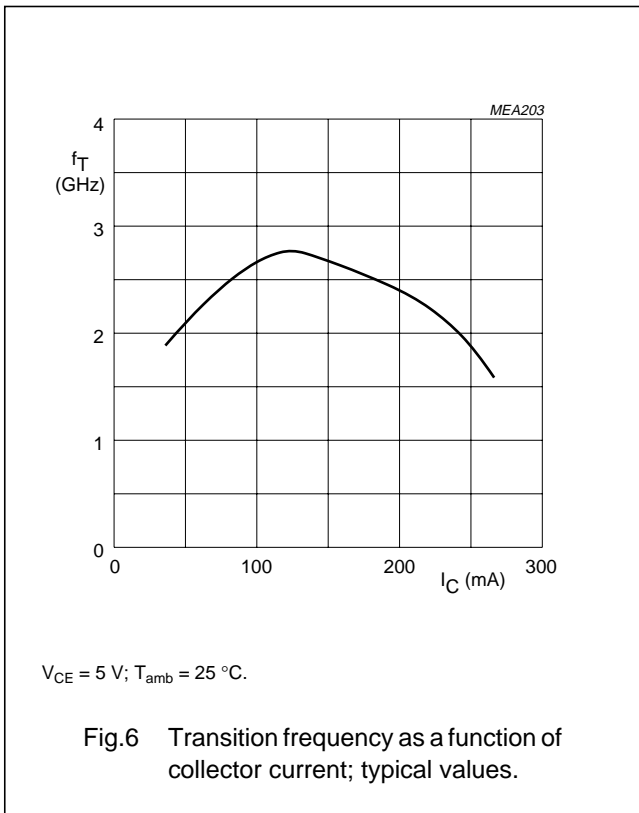
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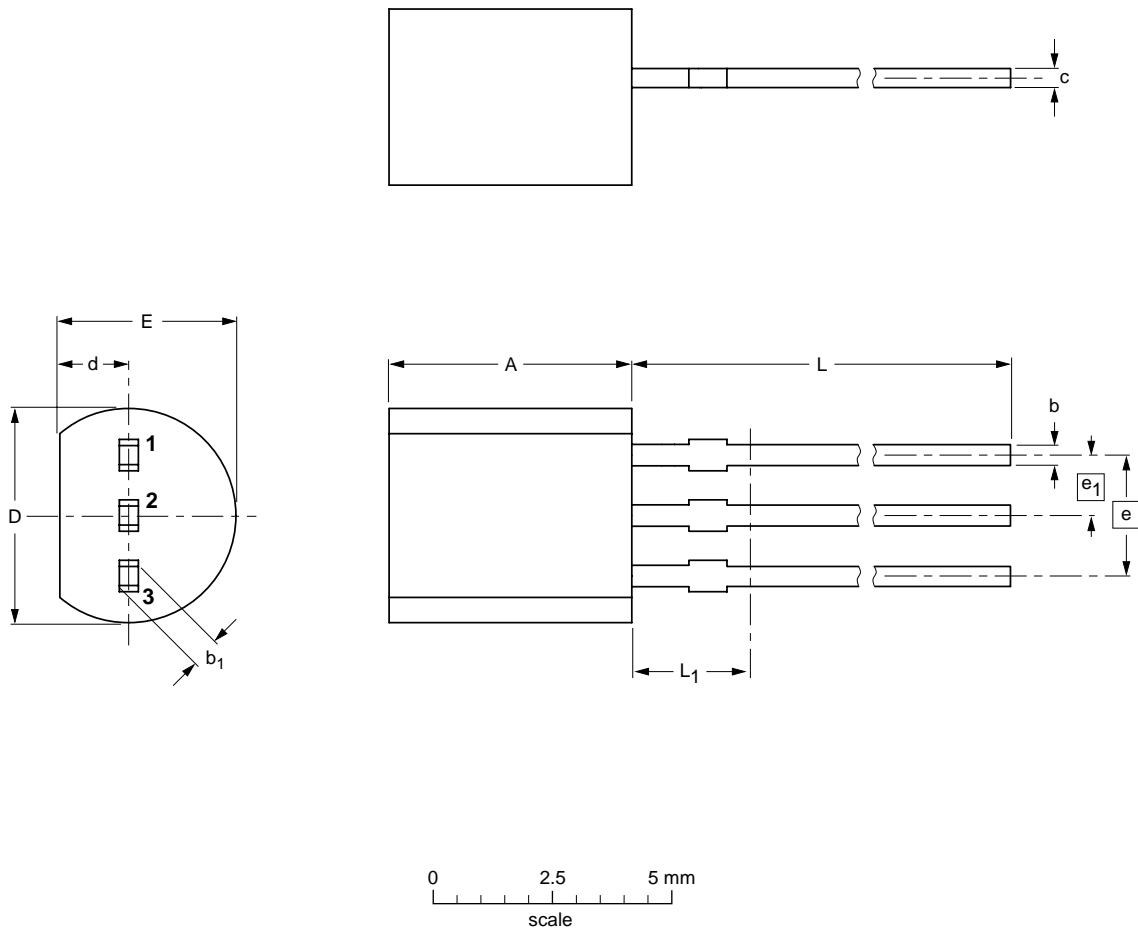
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	d	E	e	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup>
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT54		TO-92	SC-43		97-02-28

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<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
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